

Matteo Rapisarda was born in Rome, Italy, in 1980. He received a master degree in Physics from “Università di Roma Tor Vergata” in 2005 and PhD degree in physics from “Università Roma Tre” in 2010. From 2006 to 2008 he has carried out his research activity at IFN-CNR, (Institute for Photonics and Nanotechnology), in Rome, working on characterization and modeling of polysilicon TFTs. In 2008 he joined IMM-CNR (Institute for Microelectronics and Microsystems), where he works as a researcher. His main activities focus on fabrication, characterization and modeling of Organic Thin Film Transistors. He’s taken part in many international conferences on TFTs giving his contribution with several works and presentations.